

<IGBT Modules> CM1000DX-24T/CM1000DXP-24T

HIGH POWER SWITCHING USE INSULATED TYPE

	a the sharest	Collector current I _C 1 0 0 0 A				
		Collector-emitter voltage V _{CES} 1 2 0 0 V				
	•	Maximum junction temperature T _{vjmax} 1 7 5 °C				
DX		●Flat base type				
		 Copper base plate (Nickel-plating) 				
		 RoHS Directive compliant 				
		●Tin-plating pin terminals				
		Collector current Ic 1000A				
		Collector-emitter voltage V _{CES} 1 2 0 0 V				
	-	Maximum junction temperature T _{vjmax} 1 7 5 °C				
DXP		●Flat base type				
		 Copper base plate (Nickel-plating) 				
	-B.	 RoHS Directive compliant 				
		 Tin-plating pressfit terminals 				
	dual switch (half-bridge)	●UL Recognized under UL1557, File No. E323585				

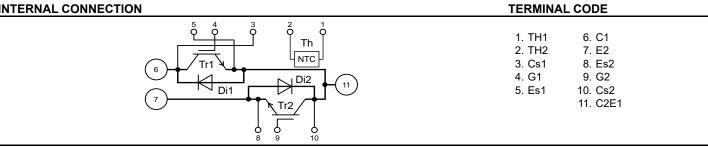
APPLICATION

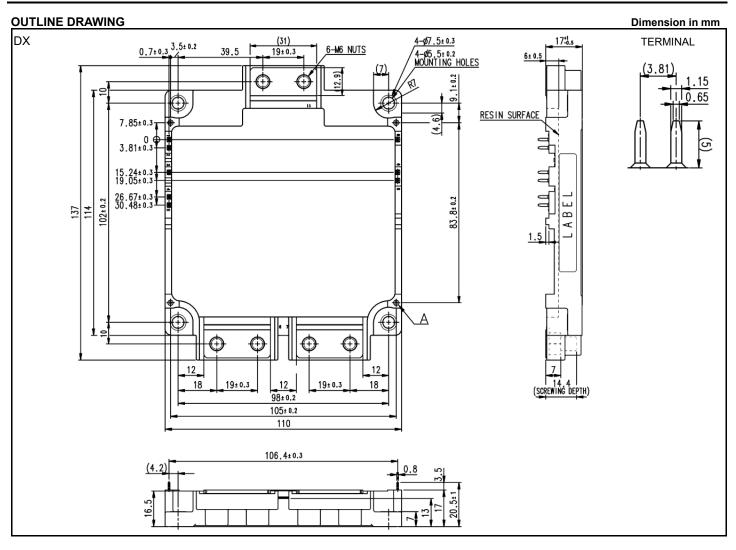
AC Motor Control, Motion/Servo Control, Power supply, etc.

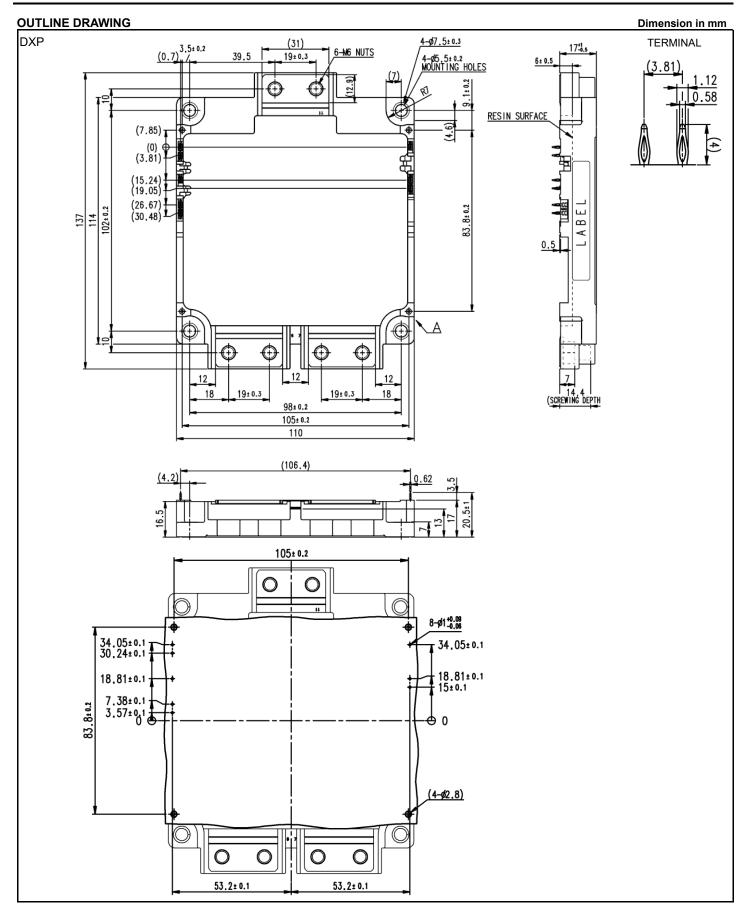
OPTION (Below options are available.)

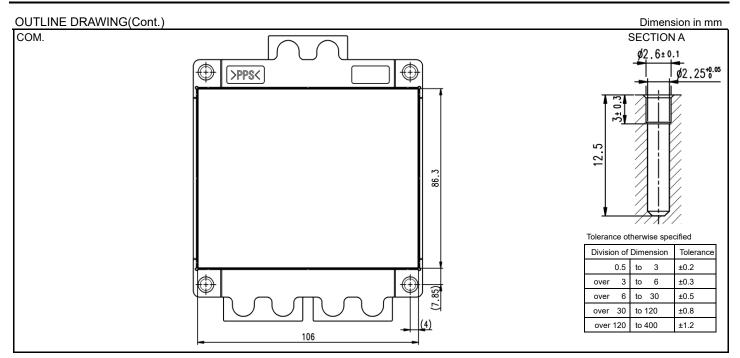
- •PC-TIM (Phase Change Thermal Interface Material) pre-apply (Note10)
- •V_{CEsat} selection for parallel connection

INTERNAL CONNECTION









MAXIMUM RATINGS (T_{vj}=25 °C, unless otherwise specified) INVERTER PART IGBT/FWD

Symbol	Item	Conditions	Rating	Unit	
V _{CES}	Collector-emitter voltage	G-E short-circuited	1200	V	
V_{GES}	Gate-emitter voltage	C-E short-circuited	± 20	V	
lc		DC, T _C =116 °C (Note2, 4)	1000	A	
I _{CRM}	Collector current	Pulse, Repetitive (Note3)	2000		
Ptot	Total power dissipation	T _C =25 °C (Note2, 4)	5355	W	
IE (Note1)	Emitter eurrent	DC (Note2)	1000	٨	
IERM (Note1)	Emitter current	Pulse, Repetitive (Note3)	2000	A	

MODULE

WODULL				
Symbol	Item	Conditions	Rating	Unit
Visol	Isolation voltage	Terminals to base plate, RMS, f=60 Hz, AC 1 min	2500	V
T _{vjmax}	Maximum junction temperature	Instantaneous event (overload) (Note10)	175	°C
T _{Cmax}	Maximum case temperature	(Note4, 10)	125	
T _{vjop}	Operating junction temperature	Continuous operation (under switching) (Note10)	-40 ~ +150	°C
T _{stg}	Storage temperature	-	-40 ~ +125	C

ELECTRICAL CHARACTERISTICS (Tvj=25 °C, unless otherwise specified) INVERTER PART IGBT/FWD

Symbol	Item Conditions			Limits		Unit	
Symbol	Item	Conditions		Min.	Тур.	Max.	Unit
ICES	Collector-emitter cut-off current	V _{CE} =V _{CES} , G-E short-circuited	-	-	1.0	mA	
I _{GES}	Gate-emitter leakage current	V _{GE} =V _{GES} , C-E short-circuited		-	-	0.5	μA
$V_{\text{GE(th)}}$	Gate-emitter threshold voltage	Ic=100 mA, V _{CE} =10 V		5.4	6.0	6.6	V
		I _C =1000 A, V _{GE} =15 V,	T _{vj} =25 °C	-	1.55	1.95	
V _{CEsat}		Refer to the figure of test circuit	T _{vj} =125 °C	-	1.70	-	V
(Terminal)		(Note5)	T _{vj} =150 °C	-	1.75	-	
	Collector-emitter saturation voltage	I _C =1000 A,	T _{vj} =25 °C	-	1.50	1.75	
V _{CEsat}		V _{GE} =15 V,	T _{vj} =125 °C	-	1.70	-	V
(Chip)		(Note5)	T _{vi} =150 °C	-	1.75	-	
Cies	Input capacitance			-	-	242.5	
Coes	Output capacitance	V _{CE} =10 V, G-E short-circuited		-	-	6.8	nF
Cres	Reverse transfer capacitance	-				3.0	
Q _G	Gate charge	V _{CC} =600 V, I _C =1000 A, V _{GE} =15 V	-	7.5	-	μC	
t _{d(on)}	Turn-on delay time		-	-	800		
t _r	Rise time	- V _{CC} =600 V, I _C =1000 A, V _{GE} =±15 V,	-	-	400	ns	
t _{d(off)}	Turn-off delay time	R _G =2.0 Ω, Inductive load		-	-		1300
t _f	Fall time			-	-		400
		I _E =1000 A, G-E short-circuited,	T _{vi} =25 °C	-	1.65	2.15	V
V _{EC} (Note1)		Refer to the figure of test circuit (Note5)	T _{vi} =125 °C	-	1.75	-	
(Terminal)			T _{vi} =150 °C	-	1.80	-	
	Emitter-collector voltage	I _E =1000 A,	T _{vj} =25 °C	-	1.60	1.95	
V _{EC} (Note1)		G-E short-circuited,	T _{vj} =125 °C	-	1.60	-	v
(Chip)		(Note5)	T _{vi} =150 °C	-	1.60	-	
t _{rr} ^(Note1)	Reverse recovery time	V _{CC} =600 V, I _E =1000 A, V _{GE} =±15 V,		-	-	500	ns
Qrr (Note1)	Reverse recovery charge	R_G =2.0 Ω, Inductive load		-	78	-	μC
Eon	Turn-on switching energy per pulse	V _{CC} =600 V, I _C =I _E =1000 A,		-	150.5	-	
E _{off}	Turn-off switching energy per pulse	V _{GE} =±15 V, R _G =2.0 Ω, T _{vi} =150 °C,		-	128.4	-	mJ
Err (Note1)	Reverse recovery energy per pulse	Inductive load		-	69	-	mJ
$R_{CC'+EE'}$	Internal lead resistance	Main terminals-chip, per switch, T _c =25	5 °C (Note4)	-	0.5	-	mΩ
r _g	Internal gate resistance	Per switch		-	0.4	-	Ω
NTC THE	RMISTOR PART	·			·	•	
		0			Limits		11.11
Symbol	Item	Conditions		Min	Typ	Max	Unit

Svmbol	Item	Conditions				Unit
Symbol		Conditions	Min.	Тур.	Max.	Unit
R ₂₅	Zero-power resistance	T _c =25 °C (Note4)	4.85	5.00	5.15	kΩ
ΔR/R	Deviation of resistance	R ₁₀₀ =493 Ω, T _C =100 °C (Note4)	-7.3	-	+7.8	%
B _(25/50)	B-constant	Approximate by equation (Note6)	-	3375	-	К
P ₂₅	Power dissipation	T _c =25 °C (Note4)	-	-	10	mW

THERMAL RESISTANCE CHARACTERISTICS

Symbol	Itom	Conditions		Limits			Unit
Symbol Item		Conditions		Min.	Тур.	Max.	Unit
$R_{th(j-c)Q}$	Junction to case, per Inverter IGBT (Note4)			-	-	28	K/kW
$R_{th(j-c)D}$	Thermal resistance	er Inverter FWD (Note4)	-	-	49	N/KVV	
В			Thermal grease applied (Note4, 7, 10)	-	7.1	-	K/kW
$R_{th(c-s)}$	Contact thermal resistance	per 1 module,	PC-TIM applied (Note4, 8, 10)	-	1.9	-	rv/KVV

MECHANICAL CHARACTERISTICS

Symbol	ltere	6	Conditions		Limits		
Symbol	Item	Con			Тур.	Max.	Unit
M _t	Mounting torque	Main terminals	M 6 screw	3.5	4.0	4.5	N∙m
Ms	Mounting torque	Mounting to heat sink	M 5 screw	2.5	3.0	3.5	N∙m
ds		Solder nin tyme (DV)	Terminal to terminal	17.3	-	-	mm
	Creepage distance	Solder pin type (DX)	Terminal to base plate	17.5	-	-	
			Terminal to terminal	16.5	-	-	mm
		Pressfit pin type (DXP)	Terminal to base plate	18.0	-	-	
	Clearance	Coldennia turne (DV)	Terminal to terminal	10.3	-	-	mm
		Solder pin type (DX)	Terminal to base plate	11.7	-	-	
da			Terminal to terminal	10.2	-	-	
		Pressfit pin type (DXP)	Terminal to base plate	11.8	-	-	mm
ec	Flatness of base plate	On the centerline X, Y	On the centerline X, Y (Note9)		-	+200	μm
m	mass	-	-		490	-	g

*. This product is compliant with the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment (RoHS) directive 2011/65/EU and (EU) 2015/863.

Note1. Represent ratings and characteristics of the anti-parallel, emitter-collector free-wheeling diode (FWD).

2. Junction temperature (T $_{\nu j}$) should not increase beyond T $_{\nu j\,m\,a\,x}$ rating.

3. Pulse width and repetition rate should be such that the device junction temperature (T_{vj}) dose not exceed T_{vjmax} rating.

4. Case temperature (T_C) and heat sink temperature (T_S) are defined on the each surface (mounting side) of base plate and heat sink just under the chips. Refer to the figure of chip location.

5. Pulse width and repetition rate should be such as to cause negligible temperature rise. Refer to the figure of test circuit.

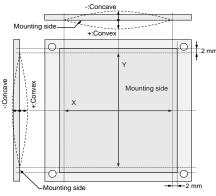
6.
$$B_{(25/50)} = ln(\frac{R_{25}}{R_{50}})/(\frac{1}{T_{25}} - \frac{1}{T_{50}})$$

 $R_{25}\!\!:$ resistance at absolute temperature T_{25} [K]; $T_{25}\!\!=\!\!25$ [°C]+273.15=298.15 [K]

 R_{50} : resistance at absolute temperature T_{50} [K]; $T_{50}{=}50$ [°C]+273.15=323.15 [K]

7. Typical value is by thermally conductive grease of $\lambda {=} 0.9$ W/(m·K)/D_(C-S)=50 $\mu m.$

- 8. Typical value is by PC-TIM of λ =3.4 W/(m·K)/D_(C-S)=50 µm.
- 9. The base plate (mounting side) flatness measurement points (X, Y) are shown in the following figure.



10. Long term performance related to thermal conductive grease and PC-TIM (including but not limited to aspects such as the increase of thermal resistance due to pumping out, etc.) should be verified under your specific application conditions. Each temperature condition (T_{vj max}, T_{vj op}, T_{C max}) must be maintained below the maximum rated temperature throughout consideration of the temperature rise even for long term usage.

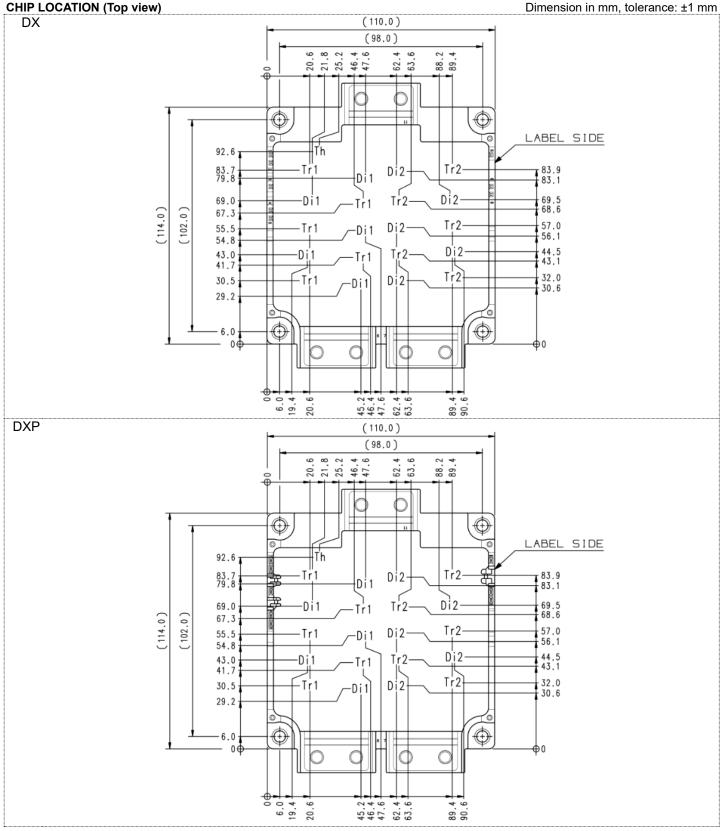
Note11. Use the following screws when mounting the printed circuit board (PCB) on the standoffs.

PCB thickness : t1.6 Tightening torque Manufacturer Size Recommended tightening method Туре (N•m) PT® EJOT K25×8 0.55 ± 0.055 (1) (2) PT® K25×10 0.75 ± 0.075 N⋅m by handwork (equivalent to 30 rpm (3) DELTA PT® 25×8 0.55 ± 0.055 N•m by mechanical screw driver) (4) DELTA PT® 25×10 0.75 ± 0.075 N∙m ~ 600 rpm (by mechanical screw driver) B1 φ2.6×10 (5) 0.75 ± 0.075 N•m tapping screw φ2.6×12

RECOMMENDED OPERATING CONDITIONS

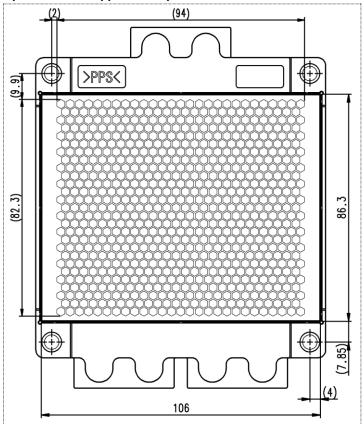
Symbol Item	ltom	Conditions	Limits			Unit
	Item	Conditions	Min.	Тур.	Max.	Unit
V _{cc}	(DC) Supply voltage	Applied across C1-E2 terminals	-	600	850	V
V_{GEon}	Gate (-emitter drive) voltage	Applied across G1-E1s/G2-E2s terminals	13.5	15.0	16.5	V
R _G	External gate resistance	Per switch	2.0	-	20	Ω

CHIP LOCATION (Top view)

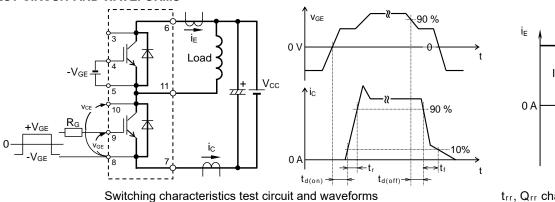


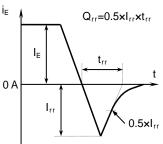
Tr1/Tr2: IGBT, Di1/Di2: FWD, Th: NTC thermistor

Option: PC-TIM applied baseplate outline



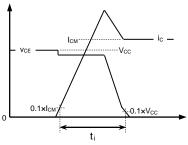


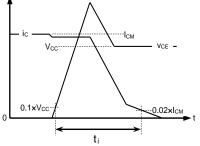




trr, Qrr characteristics test waveform

VEC





Vcc 0 A ٥ \

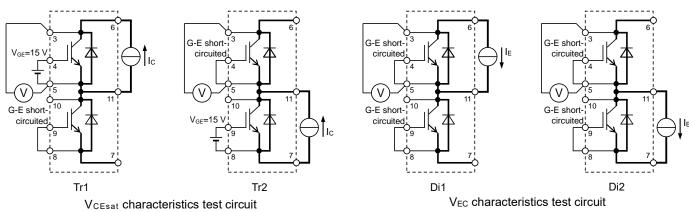
t:

-IEM

IGBT Turn-on switching energy IGBT Turn-off switching energy

FWD Reverse recovery energy Switching energy and Reverse recovery energy test waveforms (Integral time instruction drawing)

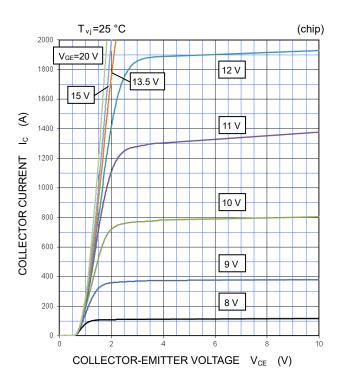
TEST CIRCUIT



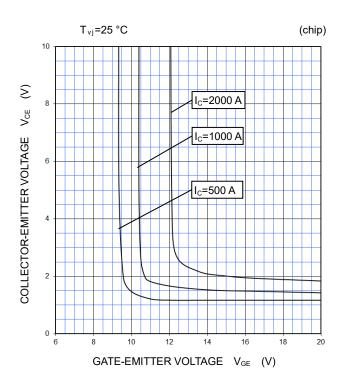
PERFORMANCE CURVES

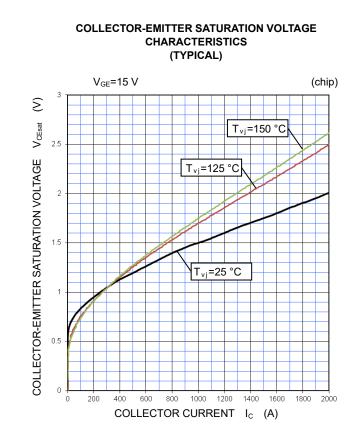
INVERTER PART



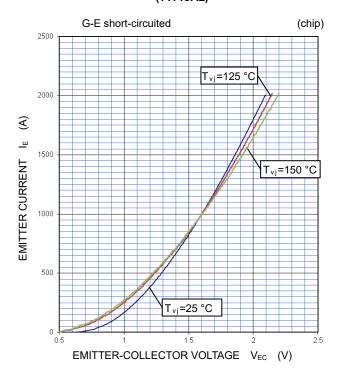


COLLECTOR-EMITTER VOLTAGE CHARACTERISTICS (TYPICAL)





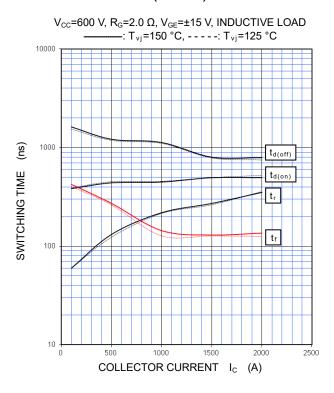
FREE WHEELING DIODE FORWARD CHARACTERISTICS (TYPICAL)



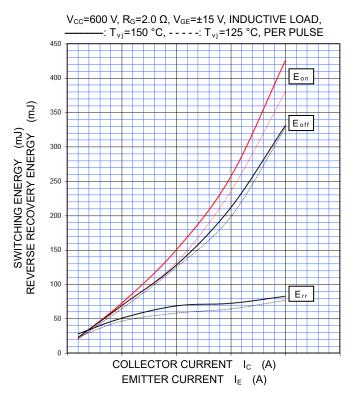
PERFORMANCE CURVES

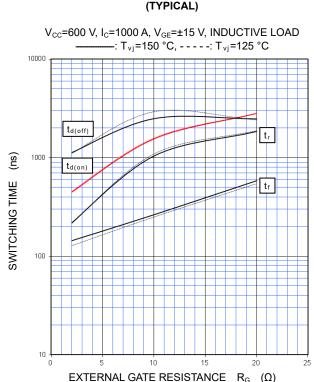
INVERTER PART

HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)

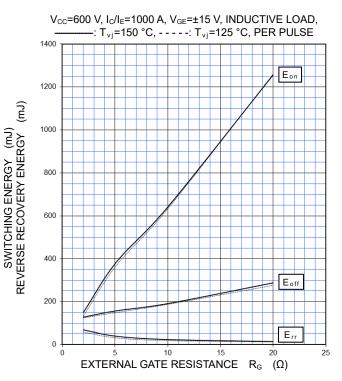


HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)





HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)

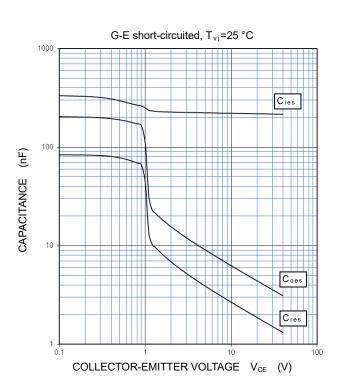


HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)

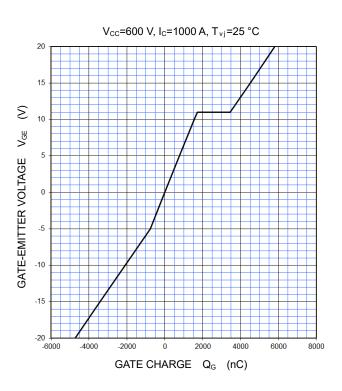
PERFORMANCE CURVES

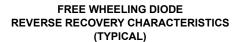
INVERTER PART

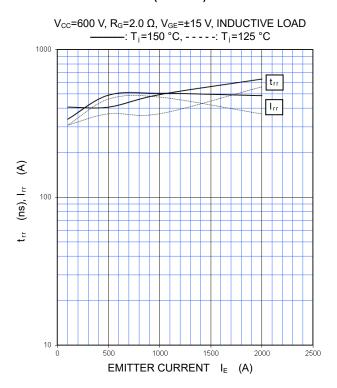
CAPACITANCE CHARACTERISTICS (TYPICAL)



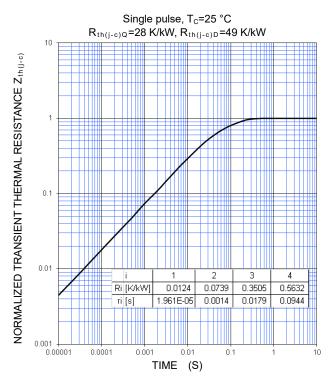
GATE CHARGE CHARACTERISTICS (TYPICAL)







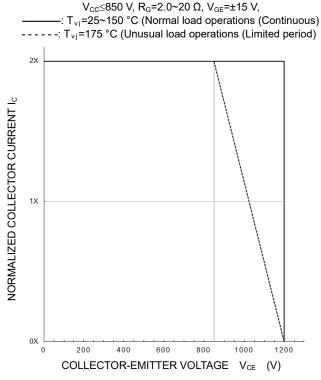
TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (MAXIMUM)



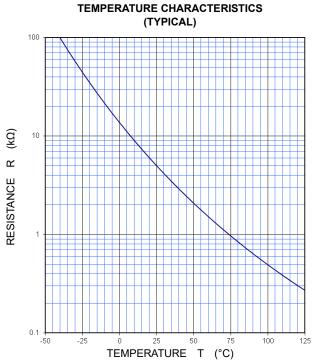
PERFORMANCE CURVES

INVERTER PART

TURN-OFF SWITCHING SAFE OPERATING AREA (REVERSE BIAS SAFE OPERATING AREA) (MAXIMUM)

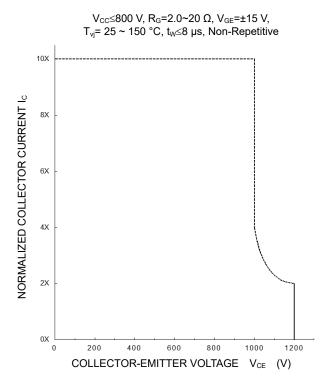


NTC thermistor part



Note: The characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

SHORT-CIRCUIT SAFE OPERATING AREA (MAXIMUM)



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